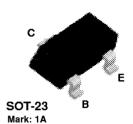


2N3904



MMBT3904



PZT3904



NPN General Purpose Amplifier

This device is designed as a general purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier. Sourced from Process 23.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	40	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	6.0	V
Ic	Collector Current - Continuous	200	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

200 50

ns

(continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 1.0 \text{ mA}, I_B = 0$	40		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 10 \mu A, I_{E} = 0$	60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I _E = 10 μA, I _C = 0	6.0		V
I _{BL}	Base Cutoff Current	V _{CE} = 30 V, V _{EB} = 0		50	nA
I _{CEX}	Collector Cutoff Current	V _{CE} = 30 V, V _{EB} = 0		50	nA
				•	•
ON CHAE	RACTERISTICS*				
h _{ee}	DC Current Gain	I _C = 0.1 mA, V _{CE} = 1.0 V	40	I	I
ITE	Do current dani	$I_C = 0.1 \text{ mA}, V_{CE} = 1.0 \text{ V}$ $I_C = 1.0 \text{ mA}, V_{CE} = 1.0 \text{ V}$	70		
		I _C = 10 mA, V _{CE} = 1.0 V	100	300	
		$I_C = 50 \text{ mA}, V_{CE} = 1.0 \text{ V}$	60		
		I _C = 100 mA, V _{CE} = 1.0 V	30		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$		0.2	V
	-	$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		0.3	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$	0.65	0.85	٧
		$I_C = 50 \text{ mA}, I_B = 5.0 \text{ mA}$		0.95	V
SMALL SI	GNAL CHARACTERISTICS				
f⊤	Current Gain - Bandwidth Product	$I_C = 10 \text{ mA}, V_{CE} = 20 \text{ V},$	300		MHz
		f = 100 MHz			
Cobo	Output Capacitance	$V_{CB} = 5.0 \text{ V}, I_E = 0,$		4.0	pF
		f = 1.0 MHz			
C_{ibo}	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_{C} = 0,$		8.0	pF
NF	Noise Figure (except MMPQ3904)	f = 1.0 MHz $I_C = 100 \mu\text{A}, V_{CE} = 5.0 \text{V},$		5.0	dB
141	Troise Figure (except wildingssor)	$R_s = 1.0kΩ$, $t = 3.0 \text{ V}$, $R_s = 1.0kΩ$, $t = 10 \text{ Hz to } 15.7 \text{ kHz}$		0.0	45
	•			•	•
SWITCHII	NG CHARACTERISTICS (except N	MMP∩3qn4\			
t _a	Delay Time	$V_{CC} = 3.0 \text{ V}, V_{BE} = 0.5 \text{ V},$		35	ns
<u>.a </u>	Rise Time	$I_{\rm C} = 10 \text{mA}, I_{\rm B1} = 1.0 \text{mA}$		35	ns

^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

Storage Time

Fall Time

Spice Model

t_f

 $NPN \ (ls=6.734f \ Xti=3 \ Eg=1.11 \ Vaf=74.03 \ Bf=416.4 \ Ne=1.259 \ ls=6.734 \ lkf=66.78m \ Xtb=1.5 \ Br=.7371 \ Nc=2 \ lsc=0 \ lkr=0 \ Rc=1 \ Cjc=3.638p \ Mjc=.3085 \ Vjc=.75 \ Fc=.5 \ Cje=4.493p \ Mje=.2593 \ Vje=.75 \ Tr=239.5n \ Tf=301.2p \ ltf=.4 \ Vtf=4 \ Xtf=2 \ Rb=10)$

 $V_{CC} = 3.0 \text{ V}, I_{C} = 10 \text{mA}$

 $I_{B1} = I_{B2} = 1.0 \text{ mA}$

(continued)

Thermal Characteristics

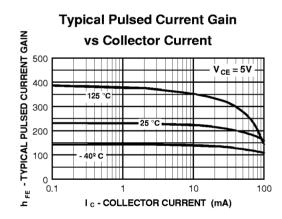
TA = 25°C unless otherwise noted

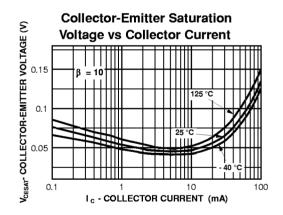
Symbol	Characteristic	Max		Units
		2N3904	*PZT3904	
P _D	Total Device Dissipation	625	1,000	mW
	Derate above 25°C	5.0	8.0	mW/°C
R _{euc}	Thermal Resistance, Junction to Case	83.3		°C/W
R _{0JA}	Thermal Resistance, Junction to Ambient	200	125	°C/W

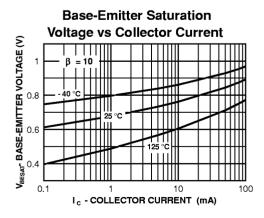
Symbol	Characteristic	Max		Units	
		**MMBT3904	MMPQ3904		
P_D	Total Device Dissipation Derate above 25°C	350 2.8	1,000 8.0	mW mW/°C	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient Effective 4 Die Each Die	357	125 240	°C/W °C/W °C/W	

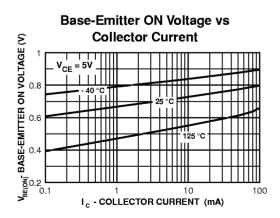
^{*}Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm².

Typical Characteristics







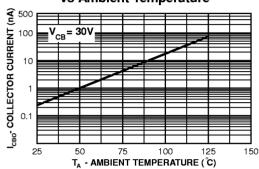


^{**}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

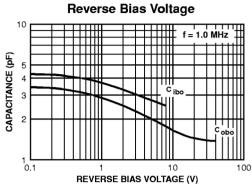
(continued)

Typical Characteristics (continued)

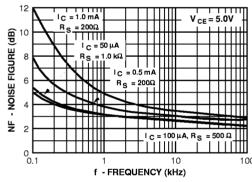




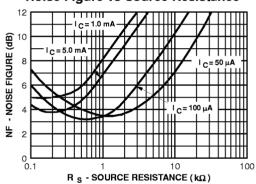
Capacitance vs Reverse Bias Voltag



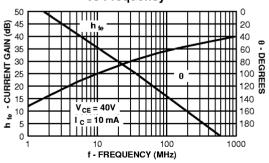
Noise Figure vs Frequency



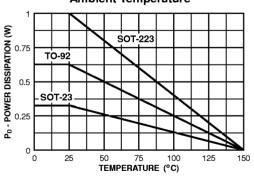
Noise Figure vs Source Resistance



Current Gain and Phase Angle vs Frequency



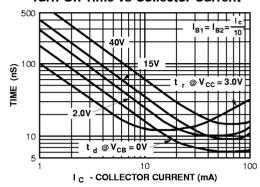
Power Dissipation vs Ambient Temperature



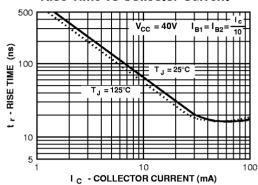
(continued)

Typical Characteristics (continued)

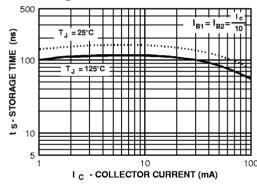
Turn-On Time vs Collector Current



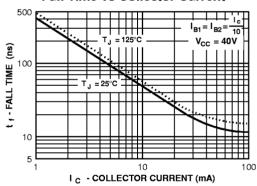
Rise Time vs Collector Current



Storage Time vs Collector Current



Fall Time vs Collector Current



(continued)

Test Circuits

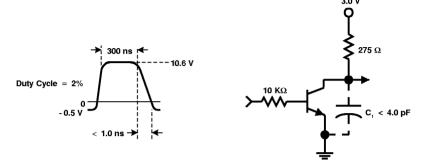


FIGURE 1: Delay and Rise Time Equivalent Test Circuit

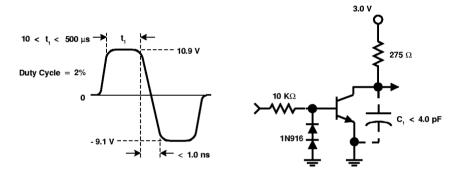


FIGURE 2: Storage and Fall Time Equivalent Test Circuit

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